

FEATURES

- **Guaranteed Low Offset Voltage**
 - LT1001AM $15\mu V$ max
 - LT1001C $60\mu V$ max
- **Guaranteed Low Drift**
 - LT1001AM $0.6\mu V/\text{°C}$ max
 - LT1001C $1.0\mu V/\text{°C}$ max
- **Guaranteed Low Bias Current**
 - LT1001AM $2nA$ max
 - LT1001C $4nA$ max
- **Guaranteed CMRR**
 - LT1001AM 114dB min
 - LT1001C 110dB min
- **Guaranteed PSRR**
 - LT1001AM 110dB min
 - LT1001C 106dB min
- **Low Power Dissipation**
 - LT1001AM 75mW max
 - LT1001C 80mW max
- **Low Noise** $0.3\mu V_{\text{p-p}}$

APPLICATIONS

- Thermocouple amplifiers
- Strain gauge amplifiers
- Low level signal processing
- High accuracy data acquisition

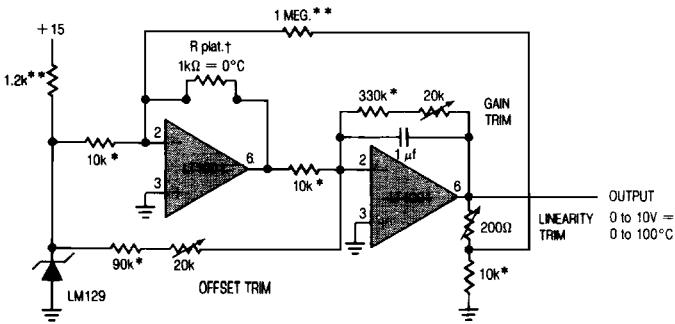
DESCRIPTION

The LT1001 significantly advances the state-of-the-art of precision operational amplifiers. In the design, processing, and testing of the device, particular attention has been paid to the optimization of the entire distribution of several key parameters. Consequently, the specifications of the lowest cost, commercial temperature device, the LT1001C, have been dramatically improved when compared to equivalent grades of competing precision amplifiers.

Essentially, the input offset voltage of all units is less than $50\mu V$ (see distribution plot below). This allows the LT1001AM/883 to be specified at $15\mu V$. Input bias and offset currents, common-mode and power supply rejection of the LT1001C offer guaranteed performance which were previously attainable only with expensive, selected grades of other devices. Power dissipation is nearly halved compared to the most popular precision op amps, without adversely affecting noise or speed performance. A beneficial by-product of lower dissipation is decreased warm-up drift. Output drive capability of the LT1001 is also enhanced with voltage gain guaranteed at 10 mA of load current. For similar performance in a dual precision op amp, with guaranteed matching specifications, see the LT1002. Shown below is a platinum resistance thermometer application.

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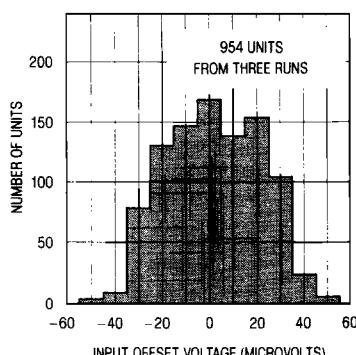
Linearized Platinum Resistance Thermometer
with $\pm 0.025^\circ\text{C}$ Accuracy Over 0 to 100°C



* ULTRONIX 105A WIREWOUND
** 1% FILM
† PLATINUM RTD
118MF (ROSEMOUNT, INC.)

† Trim sequence: trim offset ($0^\circ\text{C} = 1000.0\Omega$), trim linearity ($35^\circ\text{C} = 1138.7\Omega$), trim gain ($100^\circ\text{C} = 1392.6\Omega$). Repeat until all three points are fixed with $\pm .025^\circ\text{C}$.

Typical Distribution
of Offset Voltage
 $V_s = \pm 15V, T_A = 25^\circ\text{C}$



ABSOLUTE MAXIMUM RATINGS

Supply Voltage	$\pm 22V$
Differential Input Voltage	$\pm 30V$
Input Voltage	$\pm 22V$
Output Short Circuit Duration	Indefinite
Operating Temperature Range	
LT1001AM/LT1001M	-55°C to 150°C
LT1001AC/LT1001C	0°C to 125°C
Storage: All Devices	-65°C to 150°C
Lead Temperature (Soldering, 10 sec.)	300°C

PACKAGE/ORDER INFORMATION

TOP VIEW	ORDER PART NUMBER
 V ₋ (CASE) H PACKAGE METAL CAN	LT1001AMH/883 LT1001MH LT1001ACH LT1001CH
 J8 PACKAGE 8 PIN HERMETIC DIP	LT1001AMJ8/883 LT1001MJ8 LT1001ACJ8 LT1001CJ8
 N8 PACKAGE 8 PIN PLASTIC DIP	LT1001ACN8 LT1001CN8

ELECTRICAL CHARACTERISTICS $V_S = \pm 15V, T_A = 25^\circ C$, unless otherwise noted

SYMBOL	PARAMETER	CONDITIONS	LT1001AM/883			LT1001M/LT1001C			UNITS	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_{OS}	Input Offset Voltage	Note 1 LT1001AM/883 LT1001AC	7	15			18	60	μV	
ΔV_{OS} Δ Time	Long Term Input Offset Voltage Stability	Notes 2 and 3		0.2	1.0		0.3	1.5	$\mu V/\text{month}$	
I_{OS}	Input Offset Current			0.3	2.0		0.4	3.8	nA	
I_b	Input Bias Current			± 0.5	± 2.0		± 0.7	± 4.0	nA	
e_n	Input Noise Voltage	0.1Hz to 10Hz (Note 2)		0.3	0.6		0.3	0.6	μV_{p-p}	
e_n	Input Noise Voltage Density	$f_0 = 10\text{Hz}$ (Note 5) $f_0 = 1000\text{Hz}$ (Note 2)		10.3	18.0		10.5	18.0	$\text{nV} \sqrt{\text{Hz}}$	
A_{VOL}	Large Signal Voltage Gain	$R_L \geq 2k\Omega, V_o = \pm 12V$ $R_L \geq 1k\Omega, V_o = \pm 10V$	450	800		400	800		V/mV	
CMRR	Common Mode Rejection Ratio	$V_{CM} = \pm 13V$	114	126		110	126		dB	
PSRR	Power Supply Rejection Ratio	$V_S = \pm 3V$ to $\pm 18V$	110	123		106	123		dB	
R_{in}	Input Resistance Differential Mode	(Note 4)	30	100		15	80		MΩ	
	Input Voltage Range		± 13	± 14		± 13	± 14		V	
V_{OUT}	Maximum Output Voltage Swing	$R_L \geq 2k\Omega$ $R_L \geq 1k\Omega$	± 13	± 14	± 12	± 13	± 14	± 12	± 13.5	V
S_R	Slew Rate	$R_L \geq 2k\Omega$ (Note 4)	0.1	0.25		0.1	0.25		$V/\mu s$	
GBW	Gain-Bandwidth Product	(Note 4)	0.4	0.8		0.4	0.8		MHz	
P_d	Power Dissipation	No load No load, $V_S = \pm 3V$	46	75	4	48	80	4	mW	
					6			8		

See Notes on page 3.

ELECTRICAL CHARACTERISTICS $V_S = \pm 15V, -55^\circ C \leq T_A \leq 125^\circ C$, unless otherwise noted

SYMBOL	PARAMETER	CONDITIONS	LT1001AM/883			LT1001M			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{OS}	Input Offset Voltage		●	30	60	45	160	μV	
ΔV_{OS} Δ Temp	Average Offset Voltage Drift		●	0.2	0.6	0.3	1.0	μV/°C	
I_{OS}	Input Offset Current		●	0.8	4.0	1.2	7.6	nA	
I_B	Input Bias Current		●	± 1.0	± 4.0	± 1.5	± 8.0	nA	
A_{VOL}	Large Signal Voltage Gain	$R_L \geq 2k\Omega, V_0 = \pm 10V$	●	300	700	200	700	V/mV	
CMRR	Common Mode Rejection Ratio	$V_{CM} = \pm 13V$	●	110	122	106	120	dB	
PSRR	Power Supply Rejection Ratio	$V_S = \pm 3 \text{ to } \pm 18V$	●	104	117	100	117	dB	
	Input Voltage Range		●	± 13	± 14	± 13	± 14	V	
V_{OUT}	Output Voltage Swing	$R_L \geq 2k\Omega$	●	± 12.5	± 13.5	± 12.0	± 13.5	V	
P_d	Power Dissipation	No load	●	55	90	60	100	mW	

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 $V_S = \pm 15V, 0^\circ C \leq T_A \leq 70^\circ C$, unless otherwise noted

SYMBOL	PARAMETER	CONDITIONS	LT1001AC			LT1001C			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{OS}	Input Offset Voltage		●	20	60	30	110	μV	
ΔV_{OS} Δ Temp	Average Offset Voltage Drift		●	0.2	0.6	0.3	1.0	μV/°C	
I_{OS}	Input Offset Current		●	0.5	3.5	0.6	5.3	nA	
I_B	Input Bias Current		●	± 0.7	± 3.5	± 1.0	± 5.5	nA	
A_{VOL}	Large Signal Voltage Gain	$R_L \geq 2k\Omega, V_0 = \pm 10V$	●	350	750	250	750	V/mV	
CMRR	Common Mode Rejection Ratio	$V_{CM} = \pm 13V$	●	110	124	106	123	dB	
PSRR	Power Supply Rejection Ratio	$V_S = \pm 3V \text{ to } \pm 18V$	●	106	120	103	120	dB	
	Input Voltage Range		●	± 13	± 14	± 13	± 14	V	
V_{OUT}	Output Voltage Swing	$R_L \geq 2k\Omega$	●	± 12.5	± 13.8	± 12.5	± 13.8	V	
P_d	Power Dissipation	No load	●	50	85	55	90	mW	

The ● denotes the specifications which apply over the full operating temperature range.

Note 1: Offset voltage for the LT1001AM/883 and LT1001AC are measured after power is applied and the device is fully warmed up. All other grades are measured with high speed test equipment, approximately 1 second after power is applied. The LT1001AM/883 receives 168 hr. burn-in at 125°C. or equivalent.

Note 2: This parameter is tested on a sample basis only.

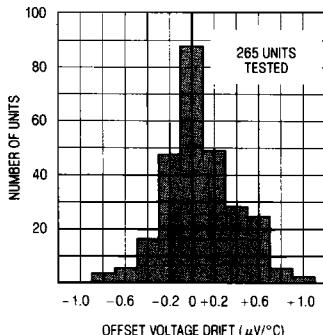
Note 3: Long Term Input Offset Voltage Stability refers to the averaged trend line of V_{OS} versus Time over extended periods after the first 30 days of operation. Excluding the initial hour of operation, changes in V_{OS} during the first 30 days are typically $2.5\mu V$.

Note 4: Parameter is guaranteed by design.

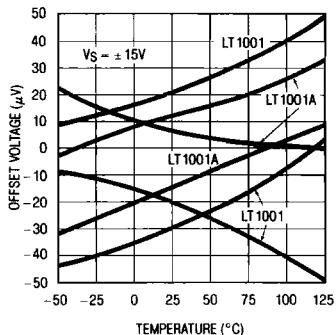
Note 5: 10Hz noise voltage density is sample tested on every lot. Devices 100% tested at 10Hz are available on request.

TYPICAL PERFORMANCE CHARACTERISTICS

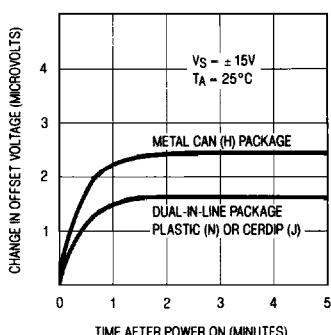
Typical Distribution of Offset Voltage Drift with Temperature



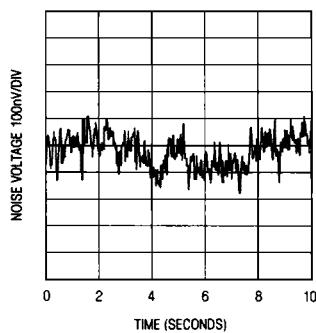
Offset Voltage Drift with Temperature of Representative Units



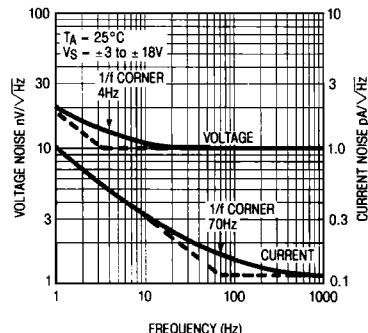
Warm-Up Drift



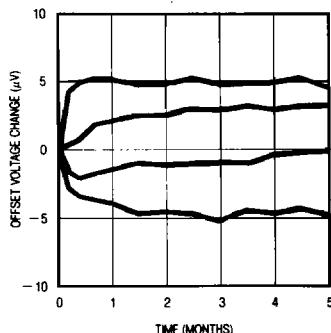
0.1Hz to 10Hz Noise



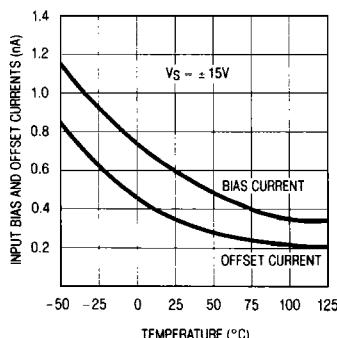
Noise Spectrum



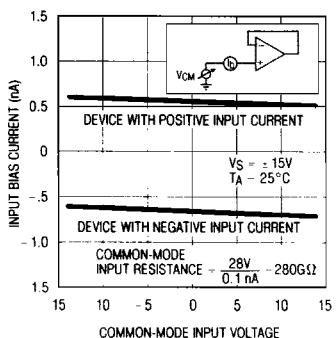
Long Term Stability of Four Representative Units



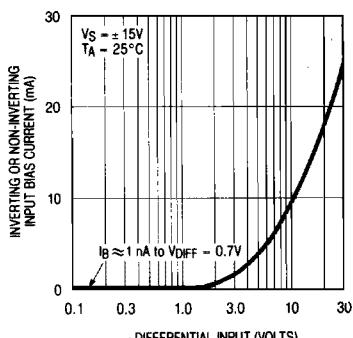
Input Bias and Offset Current vs Temperature



Input Bias Current Over the Common Mode Range

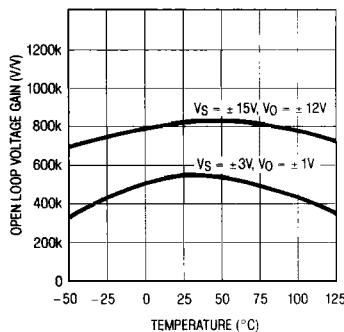


Input Bias Current vs. Differential Input Voltage

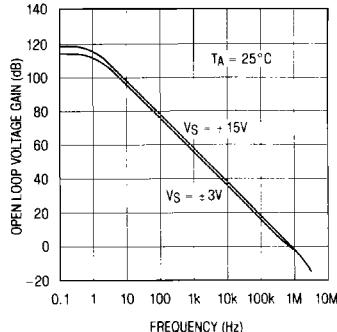


TYPICAL PERFORMANCE CHARACTERISTICS

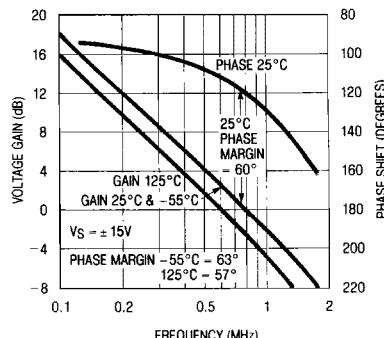
Open Loop Voltage Gain vs Temperature



Open Loop Voltage Gain Frequency Response

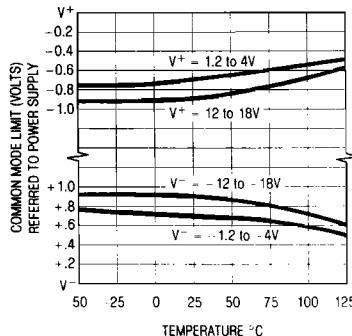


Gain, Phase Shift vs. Frequency

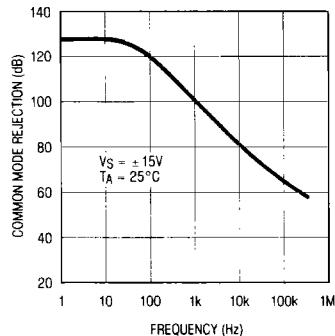


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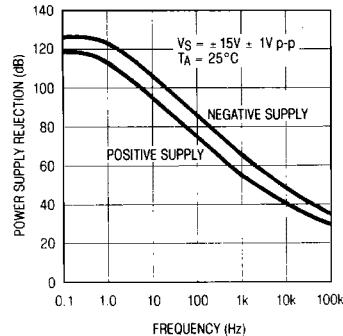
Common Mode Limit vs Temperature



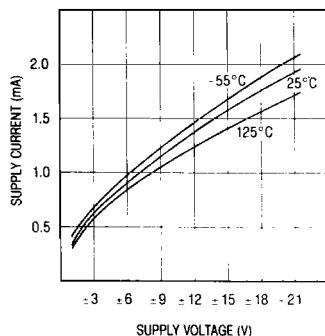
Common Mode Rejection Ratio vs Frequency



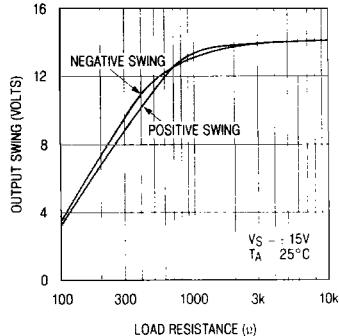
Power Supply Rejection Ratio vs Frequency



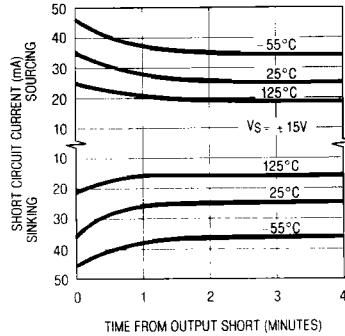
Supply Current vs Supply Voltage



Output Swing vs. Load Resistance

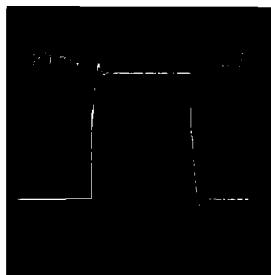


Output Short Circuit Current vs Time

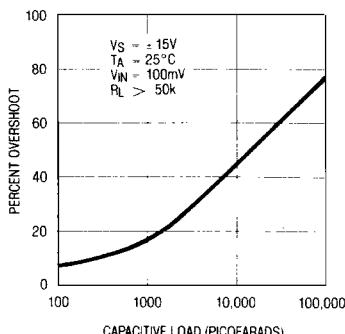


TYPICAL PERFORMANCE CHARACTERISTICS

Small Signal Transient Response

 $A_V = -1, C_L = 50\text{pF}$

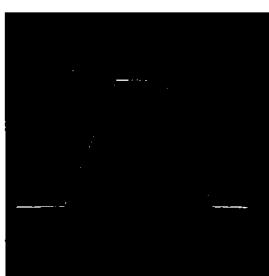
Voltage Follower Overshoot vs Capacitive Load



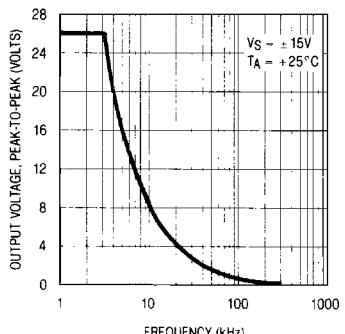
Small Signal Transient Response

 $A_V = -1, C_L = 1000\text{pF}$

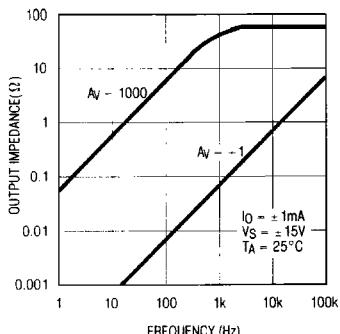
Large Signal Transient Response



Maximum Undistorted Output vs. Frequency



Closed Loop Output Impedance



APPLICATIONS INFORMATION

Application Notes and Test Circuits

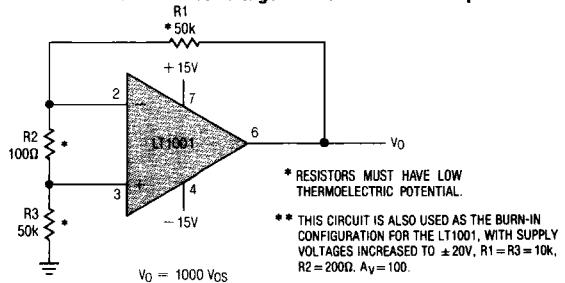
The LT1001 series units may be inserted directly into OP-07, OP-05, 725, 108A or 101A sockets with or without removal of external frequency compensation or nulling components. The LT1001 can also be used in 741, LF156 or OP-15 applications provided that the nulling circuitry is removed.

The LT1001 is specified over a wide range of power supply voltages from $\pm 3\text{V}$ to $\pm 18\text{V}$. Operation with lower supplies is possible down to $\pm 1.2\text{V}$ (two Ni-Cad batteries). However, with $\pm 1.2\text{V}$ supplies, the device is stable only in closed loop gains of +2 or higher (or inverting gain of one or higher).

Unless proper care is exercised, thermocouple effects caused by temperature gradients across dissimilar

metals at the contacts to the input terminals, can exceed the inherent drift of the amplifier. Air currents over device leads should be minimized, package leads should be short, and the two input leads should be as close together as possible and maintained at the same temperature.

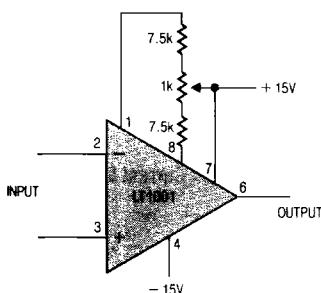
Test Circuit for Offset Voltage and its Drift with Temperature



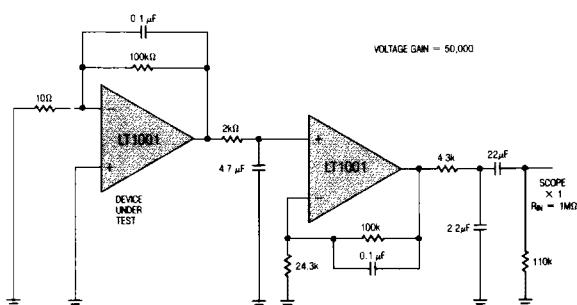
Offset Voltage Adjustment

The input offset voltage of the LT1001, and its drift with temperature, are permanently trimmed at wafer test to a low level. However, if further adjustment of V_{OS} is necessary, nulling with a 10k or 20k potentiometer will not degrade drift with temperature. Trimming to a value other than zero creates a drift of $(V_{OS}/300) \mu V/\text{ }^{\circ}\text{C}$, e.g. if V_{OS} is adjusted to 300 μV , the change in drift will be 1 $\mu\text{V}/\text{ }^{\circ}\text{C}$. The adjustment range with a 10k or 20k pot is approximately $\pm 2.5\text{mV}$. If less adjustment range is needed, the sensitivity and resolution of the nulling can be improved by using a smaller pot in conjunction with fixed resistors. The example below has an approximate null range of $\pm 100 \mu\text{V}$.

Improved Sensitivity Adjustment



0.1Hz to 10Hz Noise Test Circuit

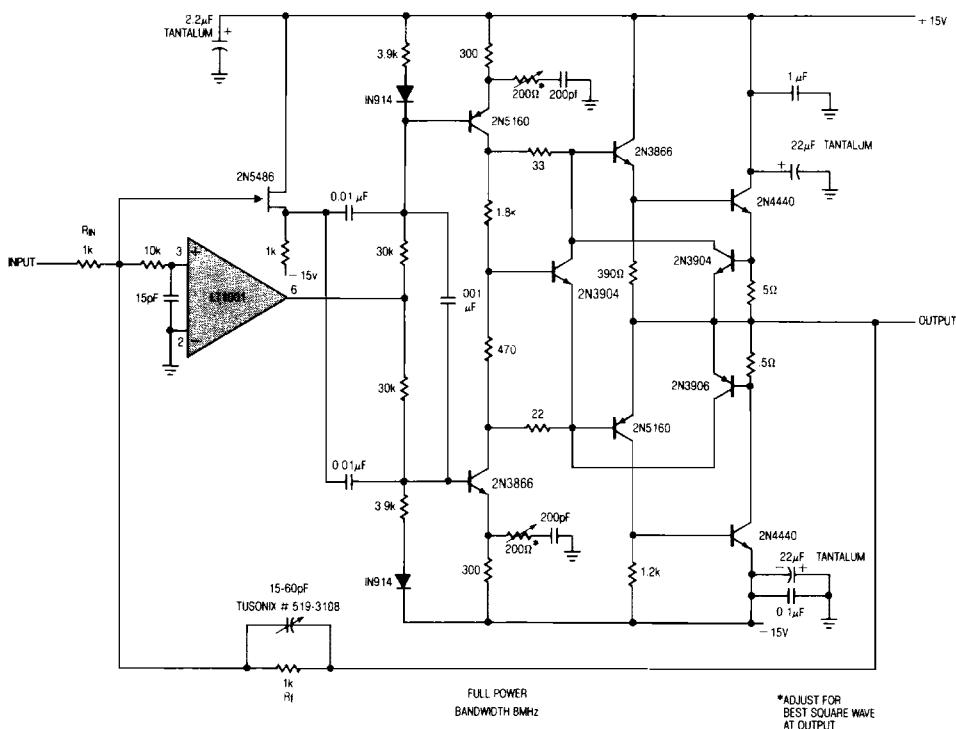


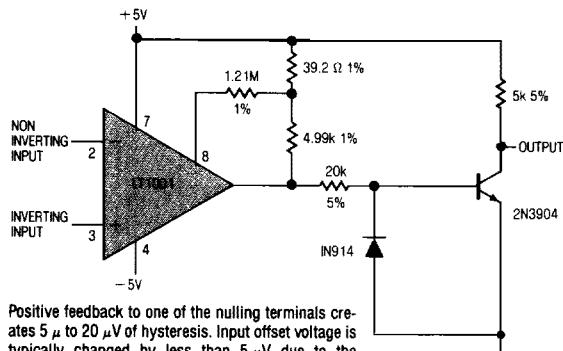
(Peak to Peak noise measured in 10 Sec interval)

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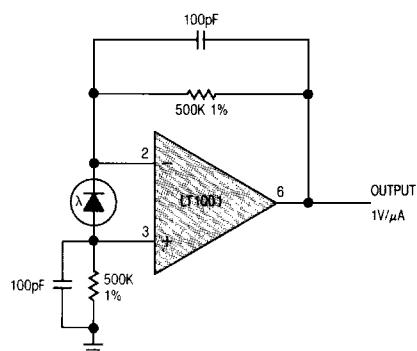
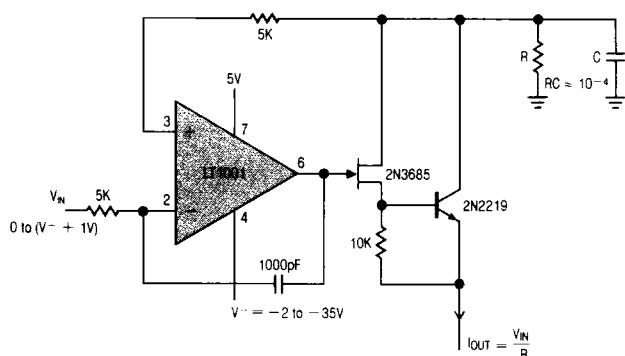
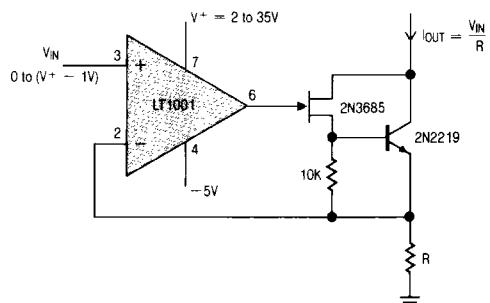
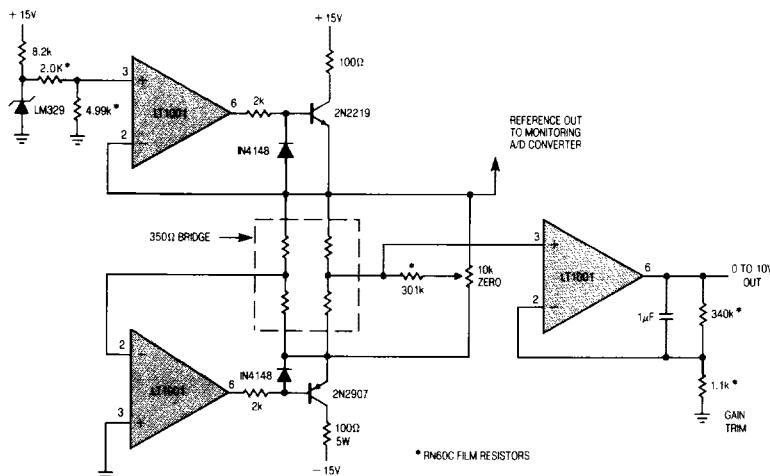
The device under test should be warmed up for three minutes and shielded from air currents.

DC Stabilized 1000v/ μsec Op Amp



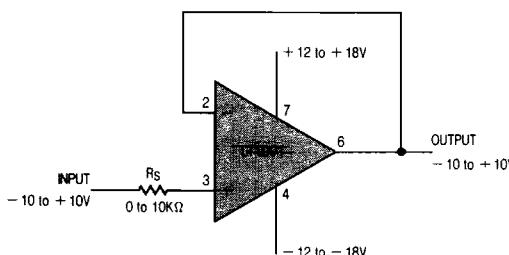
TYPICAL APPLICATIONS**Microvolt Comparator with TTL Output**

Positive feedback to one of the nulling terminals creates 5 μ V to 20 μ V of hysteresis. Input offset voltage is typically changed by less than 5 μ V due to the feedback.

Photodiode Amplifier**Precision Current Source****Precision Current Sink****Strain Gauge Signal Conditioner with Bridge Excitation**

* RN60C FILM RESISTORS

**Large Signal Voltage Follower
With 0.001% Worst-Case Accuracy**



The voltage follower is an ideal example illustrating the overall excellence of the LT1001. The contributing error terms are due to offset voltage, input bias current, voltage gain, common-mode and power-supply

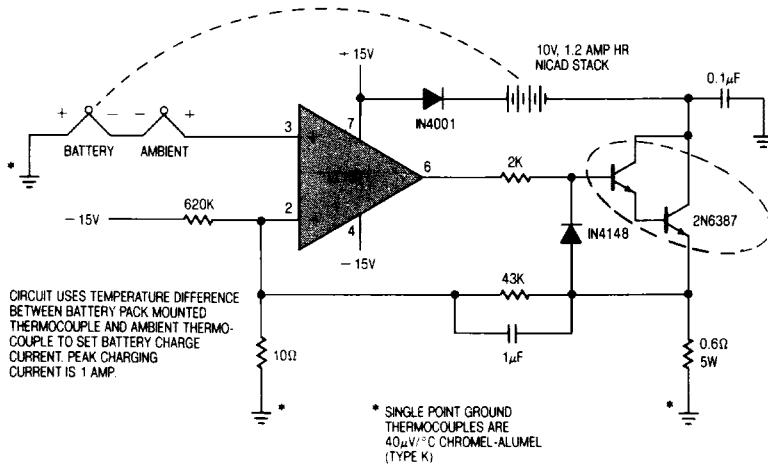
rejections. Worst-case summation of guaranteed specifications is tabulated below.

OUTPUT ACCURACY

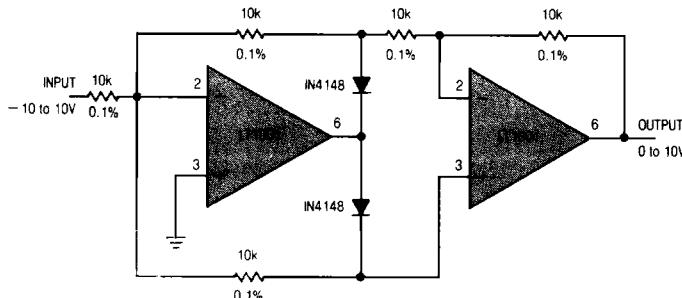
Error	LT1001AM /883	LT1001C	LT1001AM /883	LT1001C
	25°C Max.	25°C Max.	-55 to 125°C Max.	0 to 70°C Max.
Offset Voltage	15 μ V	60 μ V	60 μ V	110 μ V
Bias Current	20 μ A	40 μ A	40 μ A	55 μ A
Common-Mode Rejection	20 μ V	30 μ V	30 μ V	50 μ V
Power Supply Rejection	18 μ V	30 μ V	36 μ V	42 μ V
Voltage Gain	22 μ V	25 μ V	33 μ V	40 μ V
Worst-case Sum Percent of Full Scale (= 20V)	95 μ V	185 μ V	199 μ V	297 μ V
	0.0005%	0.0009%	0.0010%	0.0015%

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Thermally Controlled Nicad Charger

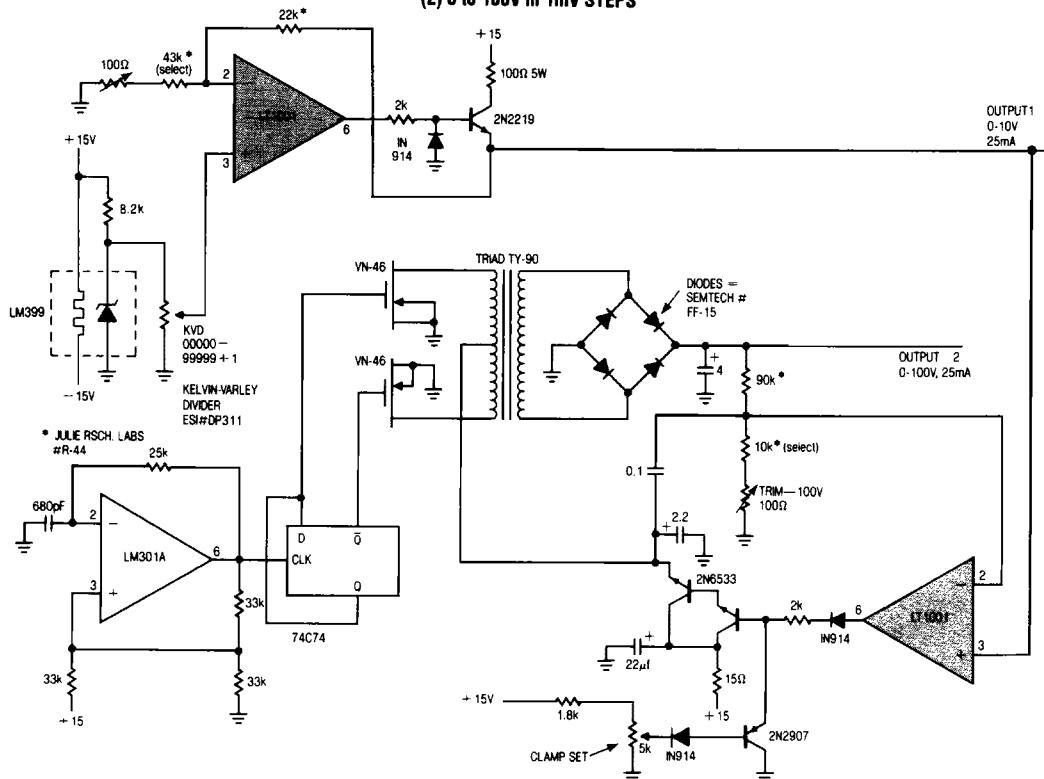


Precision Absolute Value Circuit



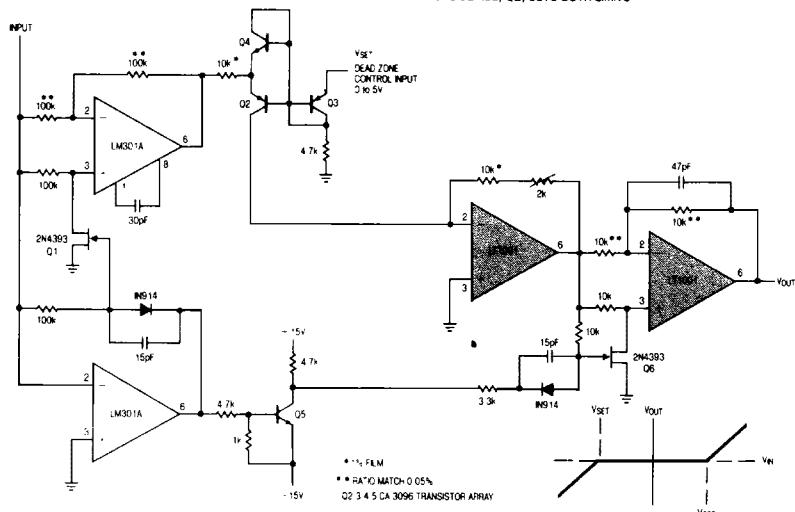
Precision Power Supply with Two Outputs

- (1) 0 to 10V in 100 μ V STEPS
- (2) 0 to 100V in 1mV STEPS

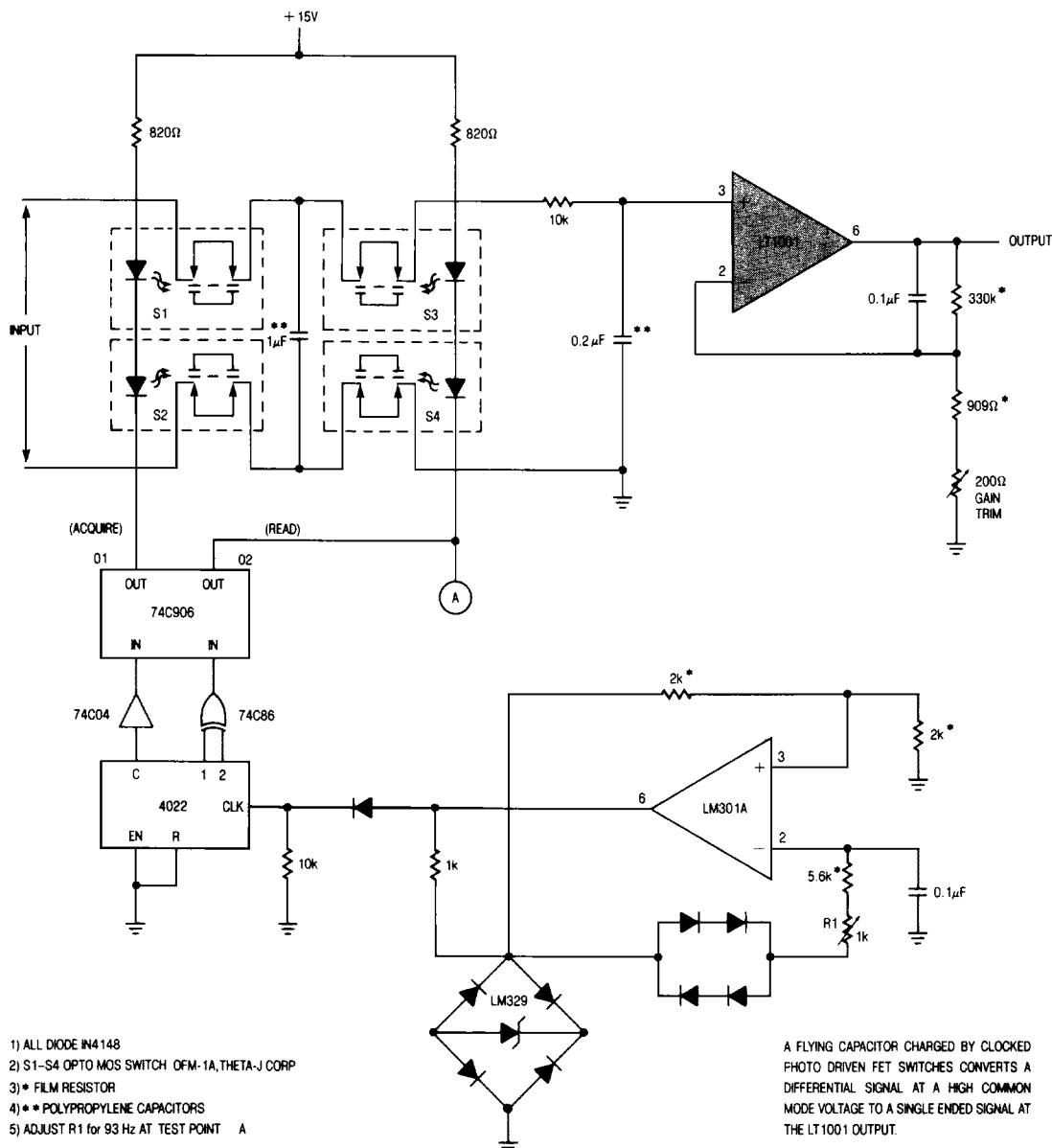


Dead Zone Generator

BIPOLAR SYMMETRY IS EXCELLENT BECAUSE ONE DEVICE, Q2, SETS BOTH LIMITS

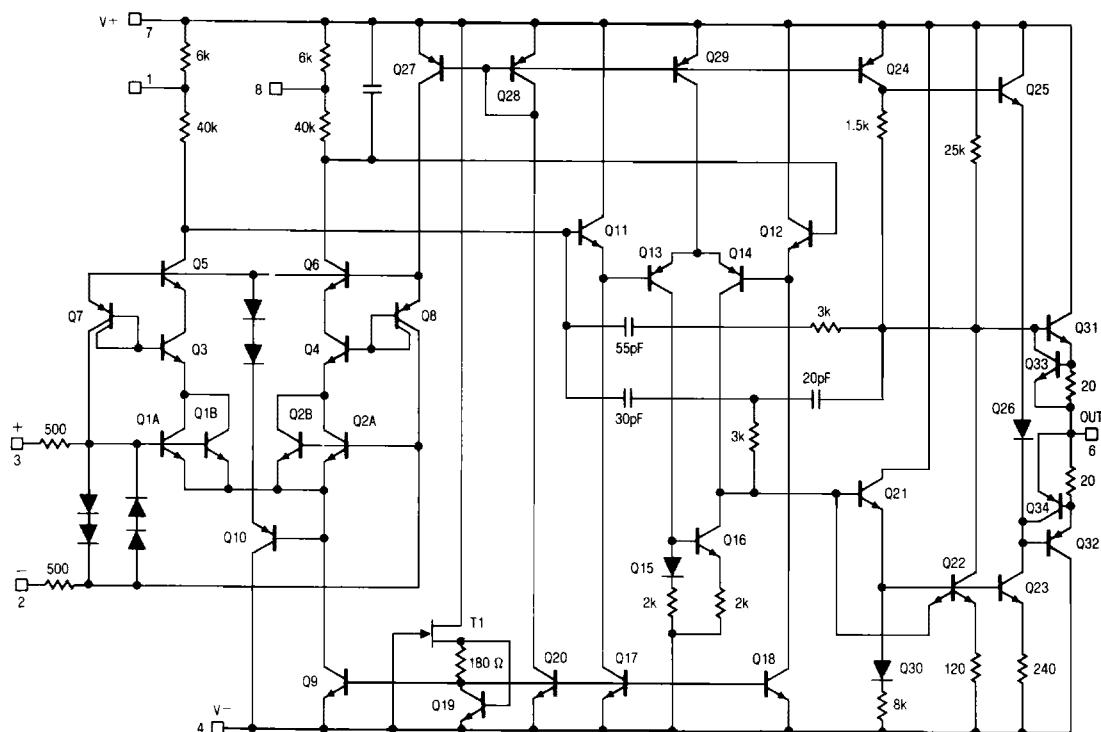


**Instrumentation Amplifier with $\pm 300V$
Common Mode Range and CMRR > 150dB**



SCHEMATIC DIAGRAM

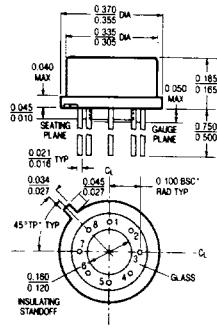
LT1001 Schematic Diagram



PACKAGE DESCRIPTION

H Package

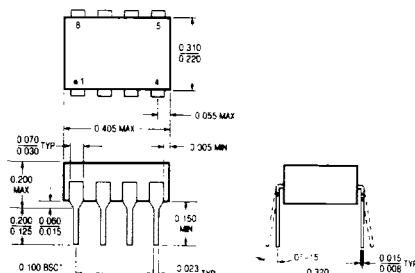
Metal Can



NOTE: DIMENSIONS IN INCHES

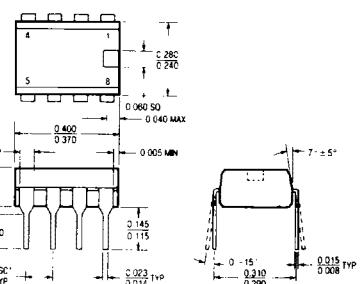
J8 Package

8 Lead Hermetic Dip

NOTE: DIMENSIONS IN INCHES UNLESS OTHERWISE NOTED
** EADS WITHIN 0.001 OF TRUE POSITION * A = GAUGE PLANE

N8 Package

8 Lead Plastic

NOTE: DIMENSIONS IN INCHES UNLESS OTHERWISE NOTED
** EADS WITHIN 0.001 OF TRUE POSITION * A = GAUGE PLANE

T _j _{max}	θ _{ja}	θ _{jc}
150°C	150°C/W	45°C/W

T _j _{max}	θ _{ja}
150°C	100°C/W

T _j _{max}	θ _{ja}
100°C	130°C/W